Title: MEMORY INTERFACE TO BRIDGE MEMORY BUSSES

Abstract: A memory interface to bridge a parallel memory bus and a serial memory bus. One embodiment includes a printed circuit board, comprising: at least one memory interface buffer chip to connect an advanced memory buffer (AMB) interface and one or more non-fully buffered memory modules.
Designated States (unless otherwise indicated, for every kind of regional protection available): ARIPO (BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

Published:
—— without international search report and to be republished upon receipt of that report

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.
MEMORY INTERFACE TO BRIDGE MEMORY BUSES

CROSS REFERENCE TO RELATED APPLICATION

This application is a continuation-in-part application of U.S. patent application serial number 11/281,211, filed November 16, 2005, and U.S. patent application serial number 11/277,650 filed March 28, 2006, the disclosure of which is incorporated herein by reference.

FIELD OF THE TECHNOLOGY

[0001] At least some embodiments of the invention relate to memory systems, and more specifically but not exclusively to memory systems with fully buffered memory modules.

BACKGROUND

[0002] Conventional memory systems use un-buffered or registered DIMMs that are connected by means of a stub bus, in which the memory modules are connected to a single channel. When the number of modules in the channel increases, the channel performance decreases and thus limits the performance of the memory system.

[0003] To increase the performance of the dynamic random access memory (DRAM) system of a computer system, the technology of Fully Buffered Dual In-line Memory Module (FB-DIMM) has been developed.
FB-DIMM technology uses high-speed, serial, point-to-point connections between memory modules and the memory controller. The host memory controller is connected to a first memory module; and a first memory module is connected to a second memory module; etc. Thus, the load of each link is constant. No branch is needed in this type of point-to-point connection. The memory modules operate at a constant load environment regardless of the number of memory modules used in the system.

Advanced Memory Buffer (AMB) is a portion of a FB-DIMM which provides the point-to-point link in the memory system. Typically, each FB-DIMM has an advanced memory buffer (AMB), which handles FB-DIMM channel and memory requests to and from the local FB-DIMM and forwards the requests to other FB-DIMMs. Such architecture can be used to design large-capacity and high-bandwidth memory subsystems for servers and workstations.

An AMB typically includes two serial ports and a parallel port. One of the serial port is for connecting to the host memory controller or the AMB of the adjacent memory module that is closer to the host memory controller; the other serial port is for connecting to the AMB of the adjacent memory module that is further away from the host memory controller; and the parallel port is for connecting to the bus to the memory chips that are on the same memory module as the AMB.

For example, serial data from the host memory controller sent through a downstream serial link to the AMB is temporarily buffered in the
AMB before being sent to the DRAM chips on the memory module. The serial data contains the address, data and command information, which is converted to parallel data in the AMB and placed onto the DRAM bus on the memory module. The AMB writes in and reads out from DRAM chips as instructed by the memory controller. The data retrieved from the DRAM is converted to serial data in the AMB and sent to the memory controller through an upstream serial link.
SUMMARY OF THE DESCRIPTION

[0008] A memory interface to bridge a parallel memory bus and a serial memory bus is described herein. Some embodiments of the invention are summarized in this section.

[0009] A printed circuit board includes at least one memory interface buffer chip to connect an advanced memory buffer (AMB) interface and one or more non-fully buffered memory modules. The printed circuit board of further includes a plurality of memory sockets configured to accept the one or more non-fully buffered memory modules; a chipset comprising a memory controller with the advanced memory buffer (AMB) interface; and a central processing unit (CPU) socket coupled to the chipset to accept a microprocessor chip.

[0010] The printed circuit board further includes a memory bus to connect the plurality of memory sockets. The memory bus comprises a Double Date Rate (DDR) memory bus.

[0011] A computer system includes a microprocessor chip; a core logic chip coupled to the microprocessor chip, the core logic chip comprising a memory controller with an advanced memory buffer (AMB) interface; one or more non-fully buffered dual in-line memory modules; and a memory interface buffer chip coupled between the advanced memory buffer (AMB) interface and the one or more non-fully buffered dual in-line memory modules.
The one or more non-fully buffered memory modules are accessed via parallel memory bus.

The computer system includes one or more fully buffered dual in-line memory modules coupled to the memory interface buffer chip.

The one or more fully buffered dual in-line memory modules is coupled between the memory interface buffer chip and the advanced memory buffer (AMB) interface.

A circuit includes a transceiver to bridge a parallel memory bus and a serial memory bus; and a protocol converter coupled to the transceiver to translate control signals received from a memory controller of the serial memory bus to control signals for the parallel memory bus.

The serial memory bus is in accordance with a Joint Electron Device Engineering Council (JEDEC) Advanced Memory Buffer (AMB) specification.

The circuit is implemented on a single integrated circuit chip. The serial memory bus is connected to an Advanced Memory Buffer (AMB) interface of a memory controller. The parallel memory bus is a double data rate (DDR) memory bus on a motherboard.

The serial memory bus is connected to an Advanced Memory Buffer (AMB) of a fully buffered memory module.
[0019] The transceiver includes a pseudo differential digital logic circuit to convert an input to the transceiver into a differential digital output.

[0020] The pseudo differential digital logic circuit is implemented using Complementary Metal-Oxide Semiconductor (CMOS). The circuit includes an adaptive power-supply regulator coupled with the pseudo differential digital logic circuit to adaptively adjust a power supply of the pseudo differential digital logic circuit.

[0021] The pseudo differential digital logic circuit includes two logic units each of which is one of: a buffer and an inverter; and a common mode feedback (CMFB) circuit coupled to the two logic units, the CMFB circuit to receive outputs of the two logic units and adjust the two logic units according to a common mode detected from the outputs of the two logic units to suppress command mode.

[0022] The pseudo differential digital logic circuit includes two logic units each of which is one of: a buffer and an inverter; and a cross couple circuit coupled to the two logic units, the cross couple circuit to cross couple outputs of the two logic units to suppress command mode in the outputs of the two logic units.

[0023] The pseudo differential digital logic circuit includes two logic units each of which is one of: a buffer and an inverter; and a clock synchronization circuit coupled to the two logic units to synchronize timing of outputs of the two logic units.

- η..
Other features of the present invention will be apparent from the accompanying drawings and from the detailed description which follows.
BRIEF DESCRIPTION OF THE DRAWINGS

[0025] The present invention is illustrated by way of example and not limitation in the figures of the accompanying drawings in which like references indicate similar elements.

[0026] Figure 1 shows a computer using a memory system according to one embodiment of the invention.

[0027] Figure 2 shows a block diagram of a memory interface buffer according to one embodiment of the invention.

[0028] Figure 3 shows a memory system architecture according to one embodiment of the invention.

[0029] Figure 4 shows a converter which can be used in a memory interface buffer according to one embodiment of the invention.

[0030] Figure 5 shows a block diagram example of a transceiver which can be used in a memory interface buffer according to one embodiment of the invention.

[0031] Figures 6-9 illustrate examples of a pseudo differential digital logic circuit which can be used in transceivers of memory interface buffers according to embodiments of the invention.
[0032] Figures 10 - 11 illustrate examples of printed circuit boards according to embodiments of the invention.

[0033] Figure 12 shows a computer using a memory system according to another embodiment of the invention.

[0034] Figures 13 - 14 show block diagrams of memory interface buffers according to embodiments of the invention.

[0035] Figure 15 shows a memory system architecture according to another embodiment of the invention.

[0036] Figure 16 illustrates an example of a printed circuit board according to one embodiment of the invention.

[0037] Figure 17 shows a memory system architecture according to further embodiment of the invention.
DETAILED DESCRIPTION OF THE INVENTION

[0038] The following description and drawings are illustrative of the invention and are not to be construed as limiting the invention. Numerous specific details are described to provide a thorough understanding of the present invention. However, in certain instances, well-known or conventional details are not described in order to avoid obscuring the description of the present invention. References to one or an embodiment in the present disclosure are not necessarily references to the same embodiment; and, such references mean at least one.

[0039] Fully Buffered - Dual-in-line Memory Modules (FB-DIMMs) are being developed to meet the increasing demand of memory capacity and bandwidth. FB-DIMM technology uses a memory controller that has an AMB interface to access FB-DIMMs. However, many current available memory controllers are capable of connecting to the conventional un-buffered or registered Dual Inline Memory Modules (DIMMs) but not to the FB-DIMMs, because of the lack of an AMB interface.

[0040] One embodiment of the invention provides a memory system architecture with a buffer on the circuit board, which may be called buffer on board, to enable the connection between a memory controller without an Advanced Memory Buffer (AMB) interface and FB-DIMMs. Thus, a conventional memory controller which lacks an AMB interface may be used with FB-DIMMs via a buffer on board. Further, the use of buffers on board according to embodiments of the invention allows the flexibility to design various hybrid memory systems.
Figure 1 shows a computer using a memory system according to one embodiment of the invention.

In Figure 1, a system includes a number of memory modules (21, 23, ..., 29). Each of the memory modules (21, 23, ..., 29) includes a number of memory chips. For example, the memory module (21) has memory chips (31, 32, ..., 33); the memory module (23) has memory chips (41, 42, ..., 43); and the memory module (29) has memory chips (51, 52, ..., 53).

In Figure 1, the memory modules (21, 23, ..., 29) are configured into a chain through point-to-point connections between advanced memory buffers (35, 45, ..., 55). The chain of memory modules (21, 23, ..., 29) are connected to the host memory controller (19) via memory interface buffer (61). The host memory controller (19) is typically implemented on a chipset (e.g., northbridge chip), which provides connections between the memory and the host processor (17).

In one embodiment, the memory interface buffer (61) is not part of an integrated circuit chip that contains the host memory controller (19). In one embodiment, the memory interface buffer (61) and the host memory controller (19) are integrated on two different integrated circuit chips for a flexible memory system. In one embodiment, the memory interface buffer is implemented on an integrated circuit chip and installed on a printed circuit board as a buffer on board.

In Figure 1, the host microprocessor (17) and the host memory
controller (19) are typically on different Integrated Circuit chips, although they may be implemented on the same chip. The host memory controller (19) is coupled to the host microprocessor (17) through an interconnect (11), which may include a bus, a chipset for core logic, a high-speed serial/parallel link, etc.

[0046] In Figure 1, the display controller/display device(s) (13) and the I/O controllers/I/O device(s) (15) are also coupled to the host microprocessor (17) through the interconnect (11).

[0047] In one embodiment, the connection between the memory interface buffer (61) and the host memory controller (19) is a conventional parallel connection, such that a conventional host memory controller (19) can be used with fully buffer memory modules (e.g., 21, 23, ..., 29), which uses point-to-point, serial connections to connect each other into a chain.

[0048] Figure 2 shows a block diagram of a memory interface buffer according to one embodiment of the invention. In Figure 2, a memory interface buffer (71) includes a serial to parallel converter (73) to convert serial signals from an advanced memory buffer (AMB) into parallel signals to memory controller; and a parallel to serial converter (77) to convert parallel signals from memory controller into serial signals to the memory buffer (AMB).

[0049] In Figure 2, a protocol converter (75) is used to forward the parallel signals received from the memory controller to the advanced memory buffer according to the serial protocol of the advanced memory
buffer; and the protocol converter (75) is used to forward the serial signals received from the advanced memory buffer to the memory controller according to the parallel protocol of the memory controller. In one embodiment, the memory interface buffer (71) may temporary buffer the data received and the forward the received data using the proper protocol.

[0050] Figure 3 shows a memory system architecture according to one embodiment of the invention. In Figure 3, a core logic chip (91) includes a memory controller (95) with a double data rate (DDR) memory interface (93) (or a quad data rate (QDR) memory interface, or other types of parallel memory interface). The memory interface of the memory controller is used to access memory via the memory bus (81), such as the DDR memory module(s) (89), which is optional.

[0051] In Figure 3, a memory interface buffer (81) provides an interface for the memory controller (95) to access the FB-DIMM (87) with an advanced memory buffer (AMB) (85).

[0052] In one embodiment, the memory interface buffer (81) and the FB-DIMM (and any FB-DIMM chained after the FB-DIMM) can be viewed as a conventional memory module from the point of view of the memory controller. Thus, the memory interface buffer (81) shields the serial aspect of the FB-DIMM from the memory controller. The memory interface buffer (81) and the memory controller (95) may be viewed as a memory controller with an AMB interface. Thus, the memory interface buffer (81) shields the parallel memory bus aspect of the memory controller (95) from the FB-DIMM.
In one embodiment, one or more memory interface buffer can be connected to the memory bus, when needed. Thus, multiple chains of FB-DIMMs can be used on the memory bus.

Figure 4 shows a converter which can be used in a memory interface buffer according to one embodiment of the invention. In Figure 4, a converter (101) includes pseudo differential digital logic (105) that is used to implement a receiver and an adaptive power supply regulator (103) that is coupled to the pseudo differential digital logic to adaptively adjust the voltage supply to reduce power consumption and improve power supply noise performance.

In one embodiment of the invention, the pseudo differential digital logic is used at least in the receiving portion of a memory interface buffer for the serial link(s) to the adjacent advanced memory buffer.

In embodiment of the invention seeks to use CMOS based pseudo differential logic to implement a high-speed data transceiver, which can be used in the memory interface buffer. In order to further reduce the power consumption of the transceiver, one embodiment of the invention further uses an adaptive power-supply regulator to adaptively adjust the power supply to the transceiver according to the working frequency, data transition pattern, fabrication process and working temperature variations.

When the feature size of an integrated circuit is 0.18um or larger, the power supply requirement of CMOS transistors is relatively high while
the operating frequency of CMOS transistors is relatively low, in comparison with MOS transistors that are used to implement CML circuit. Thus, in such integrated circuits, a data transceiver using CML circuits can actually operate in relative high speed due to CML's low output voltage swing. Meanwhile, CML also produces less power-supply noise since it generates less current spikes related to the use of a near constant power supply current.

[0058] However, with reduced channel length of CMOS transistors, for example, 0.13um or beyond, CML loses its advantage over CMOS logic in speed because the transconductance of the MOS transistors increases only slightly and eventually saturates with channel length reduction. Although increasing the power of CML circuits considerably can increase the data transceiver's operating speed/frequency, such an approach can lead to the high power consumption of the transceiver. Thus, CML may not be suitable for use in high speed/frequency applications that requires lower power consumption.

[0059] CMOS digital logic is preferred when the feature size of CMOS is reduced to 0.13um or smaller. However, traditional CMOS logic circuit technique has the disadvantage of generating rather large current spikes, thus, higher power-supply noises.

[0060] One embodiment of the invention implements CMOS pseudo differential logic circuits in the design of high-speed/frequency data transceivers, which increases the power-supply noises immunity of the transceiver while keeps the low-power advantage of CMOS logic circuits.
CMOS logic circuits consume little power while not changing states; and the pseudo differential design of the logic circuit reduces the current spikes.

[0061] In one embodiment of the invention, an adaptive power-supply regulator is further used to reduce power consumption of the transceiver as well as to reduce the power-supply noises.

[0062] In one embodiment of the invention, the CMOS based transceiver is used for high speed data transportation, such as in the memory interface buffer, in which the data transmission speed can be above one Gigabit per second.

[0063] In one embodiment of the invention, a transceiver has substantially the same functional structure as the conventional transceiver, such as multiplexer, pre-driver, driver, data recovery, color recovery, de-multiplexer, etc.

[0064] However, in one embodiment of the invention, at least some of the MOS CML circuits used in the conventional transceiver are replaced with CMOS pseudo-different digital logic circuits. In one embodiment, the output driver is still implemented using the CML circuit due to system requirement. In one embodiment, only the output driver of the transceiver uses a MOS CML circuit.

[0065] Figure 5 shows a block diagram example of a transceiver which can be used in a memory interface buffer according to one embodiment of
the invention. In Figure 5, the adaptive power supply regulator (201) provides the voltage supply to the transceiver (203), which includes a multiplexer (231) to receive parallel input data, a pre-driver (233), a driver (235) of the interface, a pseudo differential digital logic circuit (241) to receive from the interface, a clock recovery (239), and data recovery & de-multiplexer (237) to send out parallel output data.

[0066] In an alternative embodiment of the invention, the adaptive power supply regulator does not control the power supply of the drive (235).

[0067] The pseudo differential digital logic circuit (241) may cover more or less portion of the transceiver. For example, the pseudo differential digital logic circuit may be expanded to region (243) to implement a portion of the clock recovery (239) and a portion of data recovery & de-multiplexer (237). In one embodiment, the pseudo differential digital logic circuit may be further used in multiplexer (231) and/or the pre-driver (233).

[0068] Pseudo differential digital logic use two digital signal paths, which are complimentary, and a digital circuit (e.g., a latch) that is coupled in between the two digital signal paths to ensure that the output of the digital signal paths really have opposite polarity.

[0069] Figures 6 - 9 illustrate examples of a pseudo differential digital logic circuit which can be used in transceivers of memory interface buffers according to embodiments of the invention.
In Figure 6, a differential input is converted into digital signals along two paths by inverters (301 and 303). Two inverters (305 and 307) bridges between the outputs of the inverters (301 and 303) in opposite directions to ensure that the output of the inverters (301 and 303) really have opposite polarity for the differential output.

In Figure 7(a), the pseudo differential digital logic includes a buffer (401) and an inverter (403) that converts a single-ended input into a pair of digital outputs along two paths. A common mode feedback logic block (405) is used to take the output of the buffer (401) and the output of the inverter (403), generate a feedback to the buffer (401) and the inverter (403) according to the common mode detected in the outputs and uses the feedback to adjust the buffer (401) and inverter (403) to reduce and/or eliminate the common mode, so that the differential output of opposite polarity is generated. The differential output can be further elevated in magnitude using a pair of buffers or inverters (not shown in Figure 7) along the two paths.

In Figure 7(b), the pseudo differential digital logic includes two buffers (411 and 415) to generate a digital output along one path and an inventor (413) and a buffer (417) to generate another digital output along another path. A common mode feedback (CMFB) logic block (419) is coupled to the output of the two path and the control of the buffers (415 and 417) to reduce and/or eliminate the common mode in a way similar as the common mode feedback (CMFB) logic block (405) in Figure 7(a).

Alternatively, the CMFB block (419) may control the buffer (411) and the inverter (413) to minimize the common mode.
In Figure 7(b), the buffer (417) follows the inverter (413) on the path. Alternatively, a buffer may be placed before an inverter on the path.

In Figure 8(a), the pseudo differential digital logic includes a buffer (501) and an inverter (503) that converts a single-ended input into a pair of digital outputs along two paths. A cross-coupled logic block (505) is used to cross couple the output of the buffer (501) and the output of the inverter (503) so that the differential output of opposite polarity is generated. For example, the cross couple logic block (505) can be implemented using a pair of inverters connected in opposite direction, in a way as the inverters (305 and 307) in Figure 3. The differential output can be further elevated in magnitude using a pair of buffers or inverters (not shown in Figure 8) along the two paths.

In Figure 8(b), the pseudo differential digital logic includes two buffers (511 and 515) to generate a digital output along one path and an inventor (513) and a buffer (517) to generate another digital output along another path. A cross couple logic block (519) is used to cross couple to the output of the two paths so that the outputs have opposite polarity in a way similar as the cross couple logic block (505) in Figure 8(a).

In Figure 8(b), the buffer (517) follows the inverter (513) on the path. Alternatively, a buffer may be placed before an inverter on the path.

In Figure 9, the pseudo differential digital logic includes two paths to generate two digital outputs and a clock synchronization logic
block (605) is coupled between the two digital outputs to synchronize the
clock of the digital outputs and generate the differential digital output. In
one embodiment, the clock synchronization logic includes a phase
detector and a voltage controlled oscillator (VCO). In one embodiment, the
clock synchronization logic block (605) is used to recover clock from the
input.

[0079] In Figure 9, a buffer (610) and an inverter (603) are used along
the two paths to generate the corresponding outputs that are the inputs to
the clock synchronization circuit. Alternatively, a string of a combination of
buffer(s) and/or inverter(s) can be used on each of the two paths to
generate the differential output.

[0080] When the fabrication process scales down, the voltage supply of
the transistors also comes down. The power consumption of CML circuit is
proportional to VI, where V is the voltage supply and I is the operating (bias)
current. The power consumption of CMOS PDL circuit is proportional to
CV^2f, where C is the loading capacitance, V is the voltage supply, and f is
the operating frequency.

[0081] Since the power consumption of CML circuit is a linear function
of the voltage supply V while the power consumption of CMOS digital logic
circuit is a square function of the voltage supply V, the power consumption
of CMOS digital logic circuit scales down much faster than that of CML
circuit as the voltage supply V scales down.
Thus, when advanced fabrication process (e.g., 0.13 micron or smaller) is used, for example, 0.13um or beyond, a CMOS PDL circuit consumes less power than a CML circuit.

Further more, the power consumption of a CML circuit is a function of voltage supply V and operating current I, but not a function of the operating frequency f. Thus, the power consumption of a CML circuit is independent of the nominal frequency of the signal and the data transfer pattern. Thus, a CML circuitry is typically designed to maintain full power and run at the highest possible frequency of the system for the data transfer performance.

On the other hand, the power consumption of the CMOS PDL circuit is proportional to the operating frequency f. When the operating frequency f is low, the circuitry consumes less power. In applications such as AMB where no special coding (8B/10B) is used to maintain high transition rate and DC balance, it is highly possible that there is no transition for a long period of time in which the working frequency f is 0. Since the working frequency f changes from time to time, a CMOS PDL based circuit may consume less low power statistically.

In one embodiment of the invention, an adaptive power-supply regulator is used to further reduce the power consumption of the transceiver. The power-supply regulator adaptively adjusts the power supply of the transceiver according to the working frequency, data transition pattern, fabrication process and working temperature variations.
[0086] The adaptive power-supply regulator not only reduces power consumption of the transceiver but also functions as a power-supply filter to reduce the power-supply noises.

[0087] In one embodiment, the adaptive power-supply regulator includes a Phase-Locked Loop (PLL) and a bias generator. The Phase-Locked Loop includes a phase detector (PD) (211), a loop filter (LF) (213), a voltage controlled oscillator (VCO) (217) and a frequency divider (215).

[0088] In one embodiment, the VCO of the Phase-Locked Loop (PLL) of the adaptive power-supply regulator is the same as the VCO of the clock recovery of the transceiver. In one embodiment, the VCO is implemented using CMOS logic circuits. In one embodiment, the adaptive power-supply regulator and the transceiver share the same VCO.

[0089] In one embodiment, the working frequency of the VCO in the adaptive power-supply regulator is designed to track the working frequency of the transceiver logic circuits (e.g., the highest working frequency) to optimize the power supply of the transceiver so that no extra power is wasted. Thus, the transceiver uses less power than a corresponding CML implementation.

[0090] Alternatively, Phase-Locked Loop (PLL) in the adaptive power-supply regulator can be replaced with a Delay Locked Loop (DLL).
The adaptive power-supply regulator may use a design known in the field. For example, an adaptive power-supply regulator described by J. Kim and M. A. Horowitz in "Adaptive supply serial links with sub-1V operation and per-pin clock recovery, IEEE International Solid-State Circuits Conference, vol. XLV, pp. 268 - 269, February 2002, can be used with embodiments of the invention.

A current mode logic (CML) costs more die area than digital logic but has better noise performance. Digital logic can achieve similar speed performance in deep-sub micron process. The power consumption of a digital logic is data pattern dependent, such that it consumes almost any power if there is no data activity. The current mode logic uses the same power regardless whether there is data activity or not. A general digital logic has bad noise performance. At least one embodiment of the invention uses the pseudo-differential design and the regulated power supply to improve the noise performance.

Figures 10 - 11 illustrate examples of printed circuit boards according to embodiments of the invention.

In Figure 10, a printed circuit board (701) includes a microprocessor (CPU) chip (703) (or a socket for the microprocessor) and traces to connect the microprocessor chip (703) to the northbridge chip (704), which is typically one of a chipset for the system core logic. The northbridge chip (704) contains the memory controller (705), which is connected to the memory interface buffer (707) and further connected to FB-DIMMs (e.g., 709, 711, etc.)
[0095] In one embodiment, the memory interface buffer (707) is installed directly on the printed circuit board (701). Alternatively, the memory interface buffer (707) is installed on a module that has a form factor of a conventional memory module (e.g., an un-buffered or registered DIMMs), which can be inserted into the memory sockets for the conventional memory modules.

[0096] In Figure 10, the FB-DIMMs may be connected to the memory interface buffer (707) via traces on the printed circuit board (701) (e.g., when the memory interface buffer is mounted directly on the printed circuit board), or be connected to the memory interface buffer (707) through serial cables. Multiple FB-DIMMs may be integrated in one unit, with a serial connection to the memory interface buffer (707).

[0097] In Figure 11, multiple memory interface buffers (e.g., 707 and 717) can be coupled to the memory controller (705). For example, when needed, a module containing the memory interface buffer (e.g., 707 or 717) can be installed on the printed circuit board (701) to allow the system to add more FB-DIMMs. Alternatively, one may decide to use conventional unbuffered or registered DIMMs in these sockets.

[0098] Further, in one embodiment, a memory interface buffer chip may include multiple interfaces to AMBs, such that multiple chains of FB-DIMMs may be connected to a memory interface buffer.

[0099] Further, in one embodiment, a module containing the memory interface buffer and suitable for insertion into the conventional memory
sockets may also contain an AMB and memory chips, such that the memory interface and one FB-DIMM are integrated on one module insertable in a conventional memory socket for a parallel memory bus. Once such a module is inserted in the motherboard, further FB-DIMM can be chained after the AMB of the module.

[00100] Further, in one embodiment, a module containing the memory interface buffer may include multiple interfaces to AMBs, such that multiple chains of FB-DIMMs may be connected to a module.

[00101] In one embodiment, the memory interface buffer is designed to be capable to communicate with Advanced Memory Buffer (AMB) according to a Joint Electron Device Engineering Council (JEDEC) specification.

[00102]

[00103] In one embodiment, a Buffer on Board is used to connect non-fully buffered memory module (e.g., conventional unbuffered or registered DIMMs) with an Advanced Memory Buffer (AMB) interface, such as a memory controller with an AMB interface or an AMB of a fully buffered memory module. Thus, a memory subsystem using non-fully buffered memory module (e.g., DDR DIMMS) can be used with an AMB based memory system (e.g., for improvements in speed, capacity, etc.).

[00104] In one embodiment, a Buffer on Board includes a modified AMB (Advanced Memory Buffer) with several DIMM Select signals added.
Unlike a conventional AMB chip, which is placed on a DIMM and can only drive the DRAMs on the DIMM it is located, the Buffer on Board can drive the DRAMs on different DIMMs as selected by the DIMM Select signals. The Buffer on Board receives serial data from a memory controller with an AMB interface, or an upper stream AMB, converts the data to parallel format, and forwards it to a selected unbuffered or registered DIMMs over a stub-bus. The Buffer on Board also receives parallel data from the DIMMs, converts it to serial format and sends it to the memory controller (e.g., via the AMB interface of the memory controller, or an upper stream AMB). In one embodiment, a memory controller with a DDR2 or DDR3 interface can be connected to a Memory Interface Buffer with an AMB interface for further connection to the Buffer on Board to access the DDR parallel memory bus and/or AMB serial memory bus.

[00105] In one embodiment, non-fully buffered memory modules (e.g., the unbuffered or registered DIMMs) are connected the Buffer on Board via a stub-bus. The number of DIMMs per channel (stub-bus) can be reduced (e.g., to 2 or 3) to reduce the impact of electrical discontinuity caused by the stub-bus; and the number of channels can be increased (e.g. to 6) to enlarge the capacity of the memory system. The channels may be connected in parallel to multiple ports of an AMB interface of the memory controller, or in a chain from one Buffer on Board to another Buffer on Board, or in a combination of parallel and serial connections. Thus, a memory system using conventional DIMMs can have improved performance and capacity without increasing the cost significantly.

[00106] Figure 12 shows a computer using a memory system according
to another embodiment of the invention.

[00107] In Figure 12, a system includes a number of memory modules (821, 823, ..., 829). Each of the memory modules (821, 823, ..., 829) includes a number of memory chips. For example, the memory module (821) has memory chips (831, ..., 833); the memory module (823) has memory chips (841, ..., 843); and the memory module (829) has memory chips (851, ..., 853).

[00108] In Figure 1, the memory modules (821, 823, ..., 829) are configured on a parallel memory bus (e.g., a DDR2 or DDR3 bus). The memory bus is connected to a memory interface buffer (861) which is connected to the host memory controller (819) via an advanced memory buffer (AMB) interface (863). The advanced memory buffer (AMB) interface is designed to interface with one or more AMBs of a point-to-point serial memory bus. The host memory controller (819) and/or the advanced memory buffer (AMB) interface (863) is typically implemented on a chipset (e.g., northbridge chip), which provides connections between the memory and the host processor (817).

[00109] In one embodiment, the memory interface buffer (861) is not part of an integrated circuit chip that contains the host memory controller (819). In one embodiment, the memory interface buffer (861) and the host memory controller (819) are integrated on two different integrated circuit chips for a flexible memory system. In one embodiment, the memory interface buffer is implemented on an integrated circuit chip and installed on a printed circuit board as a buffer on board.
In Figure 12, the host microprocessor (817) and the host memory controller (819) are typically on different Integrated Circuit chips, although they may be implemented on the same chip. The host memory controller (819) is coupled to the host microprocessor (817) through an interconnect (811), which may include a bus, a chipset for core logic, a high-speed serial/parallel link, etc.

In Figure 12, the display controller/display device(s) (813) and the I/O controllers/I/O device(s) (815) are also coupled to the host microprocessor (817) through the interconnect (811).

In one embodiment, the connection between the memory interface buffer (861) and the host memory controller (819) is a serial connection based on a AMB specification; and the connection between the memory interface buffer (861) and the memory modules (821, 823, ..., 829) is a parallel connection based on a DDR specification. The host memory controller (819) may be a conventional memory controller with a separate advanced memory buffer (AMB) interface (863), or a memory controller having an integrated AMB interface (863). Thus, non-fully buffered memory modules can also be used in a memory system that supports AMB based memory bus.

Figures 13 - 14 show block diagrams of memory interface buffers according to embodiments of the invention.

Figure 13 shows a block diagram of a memory interface buffer
according to one embodiment of the invention. In Figure 13, a memory interface buffer (871) includes a parallel to serial converter (873) to convert parallel signals from an DDR2/DDR3 memory bus into serial signals to an advanced memory buffer (AMB) interface; and a serial to parallel converter (877) to convert serial signals from an advanced memory buffer (AMB) interface into parallel signals on a DDR2/DDR3 memory bus.

[00115] In Figure 13, a protocol converter (875) is used to forward the parallel signals received from the DDR2/DDR3 memory bus to the advanced memory buffer (AMB) interface according to the serial protocol of the advanced memory buffer; and the protocol converter (875) is used to forward the serial signals received from the advanced memory buffer (AMB) interface to the DDR2/DDR3 memory bus according to the parallel protocol of the memory bus. In one embodiment, the memory interface buffer (871) may temporary buffer the data received and the forward the received data using the proper protocol.

[00116] Figure 14 shows a block diagram of a memory interface buffer according to one embodiment of the invention. In Figure 14, a memory interface buffer (881) includes an advanced memory buffer (833) to interface with the upper stream and down stream AMB serial bus channel. Instead of using the advanced memory buffer to control on-module memory chips, a DIMM select control logic (885) is included with the memory interface buffer (881) such the memory modules accessible over the DDR2/DDR3 memory bus is under the control of the advanced memory buffer (883). In one embodiment the advanced memory buffer (883) and the DIMM select control logic (885) are integrated on a single integrated
circuit chip. Alternative, the advanced memory buffer (883) and the DIMM select control logic are implemented on two separate memory chips which are mounted on a printed circuit board as a module.

[00117] Figure 15 shows a memory system architecture according to another embodiment of the invention. In Figure 15, a core logic chip (923) includes a memory controller (935) and an advanced memory buffer (AMB) interface (933). The memory interface buffer (921) includes one interface for a parallel memory bus, such as a double data rate (DDR) memory bus (911) (or a quad data rate (QDR) memory bus, or other types of parallel memory bus). The DDR memory modules (901, ..., 903) are under the control of the memory controller via the memory interface buffer (921).

[00118] In one embodiment, the memory interface buffer (921) further includes an interface for connecting with a downstream fully buffered DIMM (937) which has an advanced memory buffer (939).

[00119] In one embodiment, one or more fully buffered DIMM can also be inserted between the memory interface buffer (921) and the AMB interface (933) of the core logic (923).

[00120] In Figure 15, a memory interface buffer (921) provides an interface for the memory controller (935) to access the non-fully buffered DIMMs via the parallel memory bus and the FB-DIMM (939) with an advanced memory buffer (AMB) (939).

[00121] In one embodiment, the memory interface buffer (921), the DDR
memory bus (911) and the DDR memory modules (901, ..., 903) can be viewed as a fully buffered memory subsystem from the point of view of the point-to-point serial memory bus, from the AMB interface (933) to the FB-DIMM (937). Thus, the memory interface buffer (921) shields the parallel aspect of the DDR memory bus from the point-to-point serial memory bus.

[00122] In one embodiment, one or more memory interface buffers can be connected to the point-to-point serial memory bus in a chain, when needed. Thus, multiple DDR memory buses can be chained on the serial memory bus via the memory interface buffers.

[00123] Figure 16 illustrates an example of a printed circuit board according to one embodiment of the invention. In Figure 16, a printed circuit board (941) includes a microprocessor (CPU) chip (943) (or a socket for the microprocessor) and traces to connect the microprocessor chip (943) to the northbridge chip (945), which is typically one of a chipset for the system core logic. The northbridge chip (945) contains the memory controller (947) and an AMB interface (949), which is connected to the memory interface buffer (955) and further connected to FB-DIMMs (e.g., 953, 951, etc.) and DRR memory bus (957).

[00124] In one embodiment, the memory interface buffer (955) is installed directly on the printed circuit board (941). Alternatively, the memory interface buffer (955) is installed on a module that has a form factor of a conventional memory module (e.g., an un-buffered or registered DIMMs), which can be inserted into the memory sockets for the
conventional memory modules.

[00125] In Figure 16, the non-fully buffered DIMMs may be connected to the memory interface buffer (957) via traces on the printed circuit board (941) (e.g., when the memory interface buffer is mounted directly on the printed circuit board). Multiple non-fully buffered DIMMs may be integrated in one unit, with a parallel connection to the memory interface buffer (955).

[00126] Figure 17 shows a memory system architecture according to further embodiment of the invention. In Figure 17, a memory controller (977) is connected to an AMB interface (975), which is further connected to one or more fully buffered (FB) DIMMs (e.g., 965), one or more memory interface buffers (e.g., 963) and one or more further FB-DIMMs (e.g., 961) in a point-to-point serial connection.

[00127] In one embodiment, multiple chains of such point-to-point serial memory buses can be connected to multiple ports of the AMB interface (975).

[00128] In one embodiment, memory interface buffer (963) controls a DDR memory bus (e.g., DDR2 or DDR3) or other types of parallel memory bus, onto which one or more non-fully buffered memory modules (e.g., DDR memory modules 969) are installed.

[00129] In one embodiment, further memory interface buffer (971) may also be used to interface further FB-DIMMs (e.g., 973) to the DDR memory bus (967).
In the foregoing specification, the invention has been described with reference to specific exemplary embodiments thereof. It will be evident that various modifications may be made thereto without departing from the broader spirit and scope of the invention as set forth in the following claims. The specification and drawings are, accordingly, to be regarded in an illustrative sense rather than a restrictive sense.
CLAIMS

What is claimed is:

1. A printed circuit board, comprising:
   at least one memory interface buffer chip to connect an advanced memory buffer (AMB) interface and one or more non-fully buffered memory modules.

2. The printed circuit board of claim 1, further comprising:
   a plurality of memory sockets configured to accept the one or more non-fully buffered memory modules;
   a chipset comprising a memory controller with the advanced memory buffer (AMB) interface; and
   a central processing unit (CPU) socket coupled to the chipset to accept a microprocessor chip.

3. The printed circuit board of claim 1, further comprising:
   a memory bus to connect the plurality of memory sockets.

4. The printed circuit board of claim 1, wherein the memory bus comprises a Double Date Rate (DDR) memory bus.

5. A computer system, comprising:
   a microprocessor chip;
a core logic chip coupled to the microprocessor chip, the core logic chip comprising a memory controller with an advanced memory buffer (AMB) interface; one or more non-fully buffered dual in-line memory modules; and a memory interface buffer chip coupled between the advanced memory buffer (AMB) interface and the one or more non-fully buffered dual in-line memory modules.

6. The computer system of claim 5, wherein the one or more non-fully buffered memory modules are accessed via a parallel memory bus.

7. The computer system of claim 6, further comprising: one or more fully buffered dual in-line memory modules coupled to the memory interface buffer chip.

8. The computer system of claim 7, wherein the one or more fully buffered dual in-line memory modules is coupled between the memory interface buffer chip and the advanced memory buffer (AMB) interface.

9. A circuit, comprising:
a transceiver to bridge a parallel memory bus and a serial memory bus; and a protocol converter coupled to the transceiver to translate control signals received from a memory controller of the serial memory bus to control signals for the parallel memory bus.
10. The circuit of claim 9, wherein the serial memory bus is in accordance with a Joint Electron Device Engineering Council (JEDEC) Advanced Memory Buffer (AMB) specification.

11. The circuit of claim 9, wherein the circuit is implemented on a single integrated circuit chip.

12. The circuit of claim 9, wherein the serial memory bus is connected to an Advanced Memory Buffer (AMB) interface of a memory controller.

13. The circuit of claim 12, wherein the parallel memory bus is a double data rate (DDR) memory bus on a motherboard.

14. The circuit of claim 9, wherein the serial memory bus is connected to an Advanced Memory Buffer (AMB) of a fully buffered memory module.

15. The circuit of claim 9, wherein the transceiver comprises: a pseudo differential digital logic circuit to convert an input to the transceiver into a differential digital output.

16. The circuit of claim 15, wherein the pseudo differential digital logic circuit is implemented using Complementary Metal-Oxide Semiconductor (CMOS).

17. The circuit of claim 16, further comprising:
an adaptive power-supply regulator coupled with the pseudo
differential digital logic circuit to adaptively adjust a power
supply of the pseudo differential digital logic circuit.

18. The circuit of claim 16, wherein the pseudo differential digital logic
circuit comprises:
two logic units each of which is one of: a buffer and an inverter; and
a common mode feedback (CMFB) circuit coupled to the two logic
units, the CMFB circuit to receive outputs of the two logic
units and adjust the two logic units according to a common
mode detected from the outputs of the two logic units to
suppress command mode.

19. The circuit of claim 16, wherein the pseudo differential digital logic
circuit comprises:
two logic units each of which is one of: a buffer and an inverter; and
a cross couple circuit coupled to the two logic units, the cross couple
circuit to cross couple outputs of the two logic units to
suppress command mode in the outputs of the two logic
units.

20. The circuit of claim 16, wherein the pseudo differential digital logic
circuit comprises:
two logic units each of which is one of: a buffer and an inverter; and
a clock synchronization circuit coupled to the two logic units to
synchronize timing of outputs of the two logic units.
Fig. 1
Fig. 2
Fig. 4
Fig. 5
Fig. 6
Fig. 7
Fig. 8
Fig. 9
Fig. 10
Fig. 11
Fig. 12
Fig. 13
Fig. 14
Fig. 15
Fig. 16